

# LM78TXX

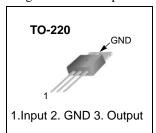
# 3-Terminal 3A Positive Voltage Regulator

#### **Features**

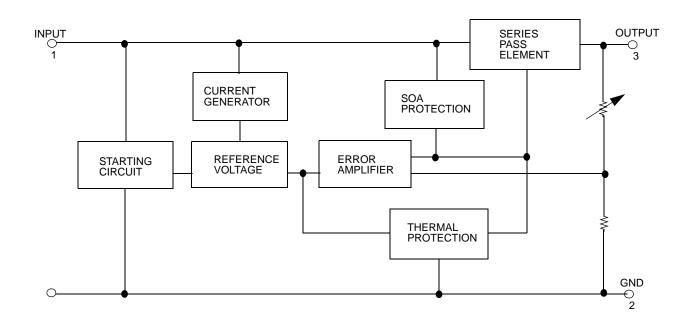
- Output Current in Excess of 3.0A
- Output Transistor Safe Operating Area Compensation
- Power Dissipation :25W
- Internal Short Circuit Current Limiting
- Internal Thermal Overload Protection
- Output Voltage Offered in 4% Tolerance
- No External Components Required
- Output Voltage of 5,12 and 15V

### **Description**

This family of fixed voltage regulators are monolithic integrated circuit capable of driving loads in excess of 3.0 A.



### **Internal Block Diagram**



## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Input Voltage (for VO = 5V to 12V) (for VO = 15V)	Vı	35 40	V V
Power Dissipation	PD	Internally limited	
Thermal Resistance, Junction to Air (Note1, 2) Ta = +25°C	RθJA	65	°C/W
Thermal Resistance, Junction to Case (Note1) Tc = +25°C	RθJC	2.5	°C/W
Operating Junction Temperature Range	TJ	0 ~ +125	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

#### Note:

- Thermal resistance test board Size: 76.2mm \* 114.3mm \* 1.6mm(1S0P) JEDEC standard: JESD51-3, JESD51-7
- 2. Assume no ambient airflow.

### **Electrical Characteristics(LM78T05)**

(VI = 10V, IO = 3.0 A,  $0^{\circ}C \le T_J \le +125^{\circ}C$ , Po  $\le P_{MAX}$  (Note3), unless otherwise specified. )

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	$5\text{mA} \le \text{lo} \le 3.0\text{A}$ , $TJ = +25^{\circ}\text{C}$ $7.3\text{V} \le \text{VI} \le 20\text{V}$ , $5\text{mA} \le \text{lo} \le 2.0\text{A}$	4.8 4.75	5.0 5.0	5.2 5.25	V
Line Regulation (Note4)	ΔVο	$7.2V \le VI \le 35V$ , $Io=5mA$ , $T_J = +25^{\circ}C$ $7.2V \le VI \le 35V$ , $Io=1.0A$ , $T_J = +25^{\circ}C$ $7.5V \le VI \le 20V$ , $Io=2.0A$ , $T_J = +25^{\circ}C$ $8.0V \le VI \le 12V$ , $Io=3.0A$ , $T_J = +25^{\circ}C$		3.0	25	mV
Load Regulation (Note4)	ΔVO	$5\text{mA} \le \text{lo} \le 3.0\text{A}$ , $T_J = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W TA = +25°C	-	0.002	0.03	%Vo/W
Quiescent Current	IQ	$5\text{mA} \le \text{lo} \le 3.0\text{A}$ , $T_J = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$7.2V \le VI \le 35V$ , $Io = 5mA$ $T_J = +25^{\circ}C$ ; $7.5V \le VI \le 20V$ , $Io = 2.0A$ ; $5mA \le Io \le 3.0A$ , $T_J = +25^{\circ}C$	-	0.1	0.8	mA
Ripple Rejection	RR	$f = 120Hz, 8V \le V_I \le 18V, I_0 = 2.0A$ $T_J = +25^{\circ}C$	-	75	-	dB
Dropout Voltage	VD	Io = 3A ,TJ = +25°C	-	2.2	2.5	V
Output Noise Voltage	VN	$T_A = +25^{\circ}C, 10Hz \le f \le 100kHz$	-	10	-	μV/Vo
Peak Output Current	IPK	T <sub>A</sub> = +25°C	-	5.0	-	Α
Output Resistance	Ro	f = 1.0kHz	-	2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 35V, T <sub>J</sub> =+25°C	-	1.5	2.5	Α
Average Temperature Coefficient of Output Voltage	ΔV0/ΔΤ	Io = 5.0mA	-	0.2	-	mV/°C

- 3. Although power dissipation is internally limited, specifications apply only for  $PO \le Pmax$ , Pmax = 25W
- 4. Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics(LM78T12) (Continued)

(VI = 19V, IO = 3.0 A,  $0^{\circ}$ C  $\leq$  TJ  $\leq$  +125 $^{\circ}$ C, Po  $\leq$  PMAX (Note1), unless otherwise specified. )

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	$5\text{mA} \le \text{lo} \le 3.0\text{A}$ , $T_J = +25^{\circ}\text{C}$ $14.5\text{V} \le \text{VI} \le 27\text{V}$ , $5\text{mA} \le \text{lo} \le 2.0\text{A}$	11.5 11.4	12 12	12.5 12.8	V
Line Regulation (Note2)	ΔVο	$\begin{array}{l} 14.5 V \leq VI \leq 35 V, \ lo=5 mA, \ T_J = +25 ^{\circ} C \\ 14.5 V \leq VI \leq 35 V, \ lo=1.0 A, \ T_J = +25 ^{\circ} C \\ 14.9 V \leq VI \leq 28 V, \ lo = 2.0 A, \ T_J = +25 ^{\circ} C \\ 16 V \leq VI \leq 22 V, \ lo = 3.0 A, \ T_J = +25 ^{\circ} C \end{array}$		6.0	45	mV
Load Regulation (Note2)	ΔVO	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{TJ} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W T <sub>A</sub> = +25°C	-	0.002	0.03	%Vo/W
Quiescent Current	IQ	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{T}_{\text{J}} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$14.5V \le VI \le 35V$ , $Io = 5mA$ $T_J = +25^{\circ}C$ ; $14.9V \le VI \le 27V$ , $Io = 2.0A$ ; $5mA \le Io \le 3.0A$ , $T_J = +25^{\circ}C$	-	0.1	0.8	mA
Ripple Rejection	RR	$f$ = 120Hz, 15V $\leq$ VI $\leq$ 25V, Io = 2.0A TJ =+25°C	-	67	-	dB
Dropout Voltage	VD	lo = 3A,T <sub>J</sub> =+25°C	-	2.2	2.5	V
Output Noise Voltage	VN	TA =+25°C, $10Hz \le f \le 100kHz$	-	10	-	μV/Vo
Peak Output Current	IPK	T <sub>A</sub> =+25°C	-	5.0	-	Α
Output Resistance	Ro	f = 1.0kHz	•	2.0	•	mΩ
Short Circuit Current Limit	Isc	VI = 35V, TJ =+25°C	-	1.5	2.5	Α
Average Temperature Coefficient of Output Voltage	ΔV0/ΔΤ	Io = 5.0mA	-	0.5	-	mV/°C

<sup>1.</sup> Although power dissipation is internally limited, specifications apply only for  $P_0 \le P_0 \le$ 

<sup>2.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used. ( PMAX = 25W)

## Electrical Characteristics(LM78T15) (Continued)

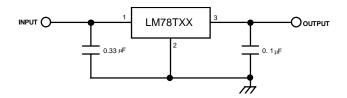
(VI = 23V, IO = 3.0 A,  $0^{\circ}$ C  $\leq$  TJ  $\leq$  +125 $^{\circ}$ C, Po  $\leq$  PMAX (Note1), unless otherwise specified. )

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{ T}_J = +25^{\circ}\text{C}$ $17.5\text{V} \le \text{VI} \le 30\text{V}, 5\text{mA} \le \text{lo} \le 2.0\text{A}$		15 15	15.6 15.75	V
Line Regulation (Note2)	ΔVο	$17.6V \le VI \le 40V$ , $Io=5mA$ , $T_J=+25^{\circ}C$ $17.6V \le VI \le 40V$ , $Io=1.0A$ , $T_J=+25^{\circ}C$ $18V \le VI \le 30V$ , $Io=2.0A$ , $T_J=+25^{\circ}C$ $20V \le VI \le 26V$ , $Io=3.0A$ , $T_J=+25^{\circ}C$		7.5	55	mV
Load Regulation (Note2)	ΔVο	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{TJ} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W T <sub>A</sub> = +25°C		0.002	0.03	%Vo/W
Quiescent Current	IQ	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{T}_J = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$17.6V \le VI \le 40V$ , $Io = 5mA$ $T_J = +25^{\circ}C$ ; $18V \le VI \le 30V$ , $Io = 2.0A$ ; $5mA \le Io \le 3.0A$ , $T_J = +25^{\circ}C$	-	0.1	0.8	mA
Ripple Rejection	RR	$ f = 120 Hz, \ 18.5 V \le V_I \le 28.5 V, \ Io = 2.0 A $ $ T_J = +25^{\circ} C $		65	-	dB
Dropout Voltage	٧D	$Io = 3A$ , $T_J = +25^{\circ}C$	-	2.2	2.5	V
Output Noise Voltage	VN	$TA = +25^{\circ}C, 10Hz \le f \le 100kHz$		10	-	μV/Vo
Peak Output Current	IPK	T <sub>A</sub> = +25°C		5.0	-	Α
Output Resistance	Ro	f = 1.0kHz	-	2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 40V, TJ = +25°C	-	1.0	2.0	Α
Average Temperature Coefficient of Output Voltage	ΔV0/ΔΤ	Io = 5.0mA	-	0.5	ı	mV/°C

<sup>1.</sup> Although power dissipation is internally limited, specifications apply only for  $P_0 \le P_0 \le$ 

<sup>2.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used. (PMAX = 25W)

## **Typical Application**



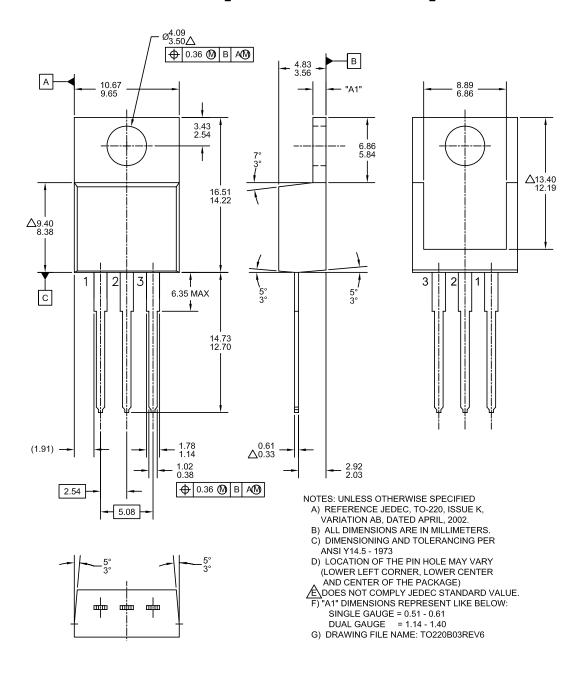
- 1. To specify an output voltage, substitute voltage value for "XX".
- Bypass Capacitors are recommend for optimum stability and transient response and should be located as close as possible to the regulator

### **Mechanical Dimensions**

### **Package**

#### **Dimensions in millimeters**

# TO-220 [ SINGLE GAUGE ]



# **Ordering Information**

Product Number	Package	Operating Temperature
LM78T05CT		
LM78T12CT	TO-220	0 ~ +125°C
LM78T15CT		

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